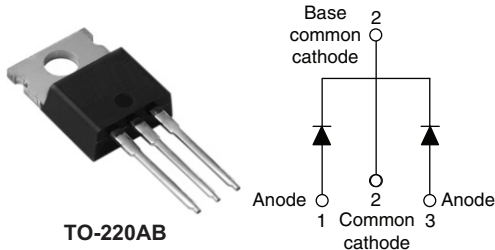


Schottky Rectifier, 2 x 15 A



FEATURES

- 150 °C T_J operation
- Center tap TO-220 package
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for industrial level

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY	
$I_{F(AV)}$	2 x 15 A
V_R	35/45 V
I_{RM}	40 mA at 125 °C

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform (per device)	30	A
V_{RRM}		35/45	V
I_{FRM}	$T_C = 130$ °C (per leg)	30	A
I_{FSM}	$t_p = 5$ μ s sine	1060	
V_F	30 Apk, $T_J = 125$ °C	0.73	V
T_J	Range	- 65 to 150	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	MBR2535CT	MBR2545CT	UNITS
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current per leg per device	$I_{F(AV)}$	$T_C = 130$ °C, rated V_R		15	A
				30	
Peak repetitive forward current per leg	I_{FRM}	Rated V_R , square wave, 20 kHz, $T_C = 130$ °C		30	
Non-repetitive peak surge current	I_{FSM}	5 μ s sine or 3 μ s rect. pulse	Following any rated load condition and with rated V_{RRM} applied	1060	
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150	
Non-repetitive avalanche energy per leg	E_{AS}	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 8$ mH		16	mJ
Repetitive avalanche current per leg	I_{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2	A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}^{(1)}$	30 A	$T_J = 25\text{ }^\circ\text{C}$	0.82	V
			$T_J = 125\text{ }^\circ\text{C}$	0.73	
Maximum instantaneous reverse current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	Rated DC voltage	0.2	mA
		$T_J = 125\text{ }^\circ\text{C}$		40	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J$ maximum		0.355	V
Forward slope resistance	r_t			12.3	m Ω
Maximum junction capacitance	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 $^\circ\text{C}$		700	pF
Typical series inductance	L_S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μs

Note

(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction temperature range	T_J			- 65 to 150	$^\circ\text{C}$
Maximum storage temperature range	T_{Stg}			- 65 to 175	
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation		1.5	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased		0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style TO-220AB		MBR2535CT	
				MBR2545CT	

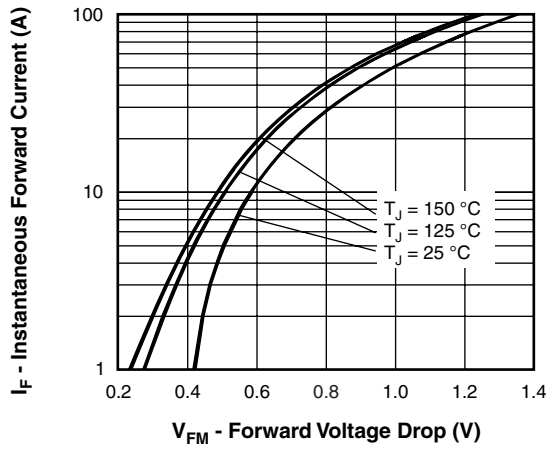


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

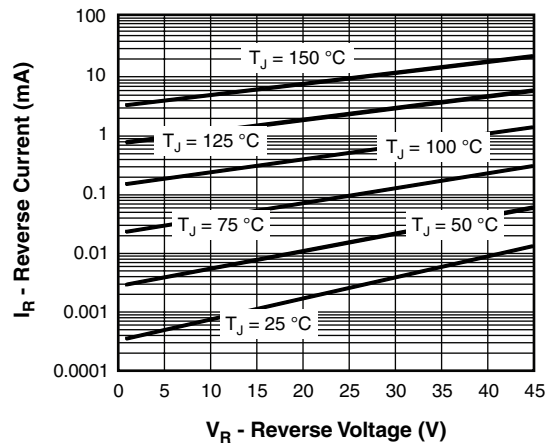


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

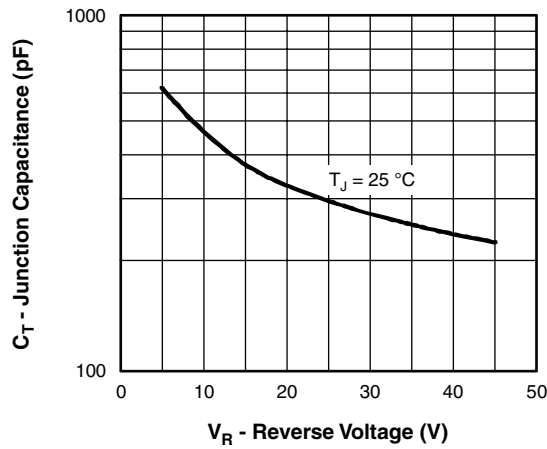


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

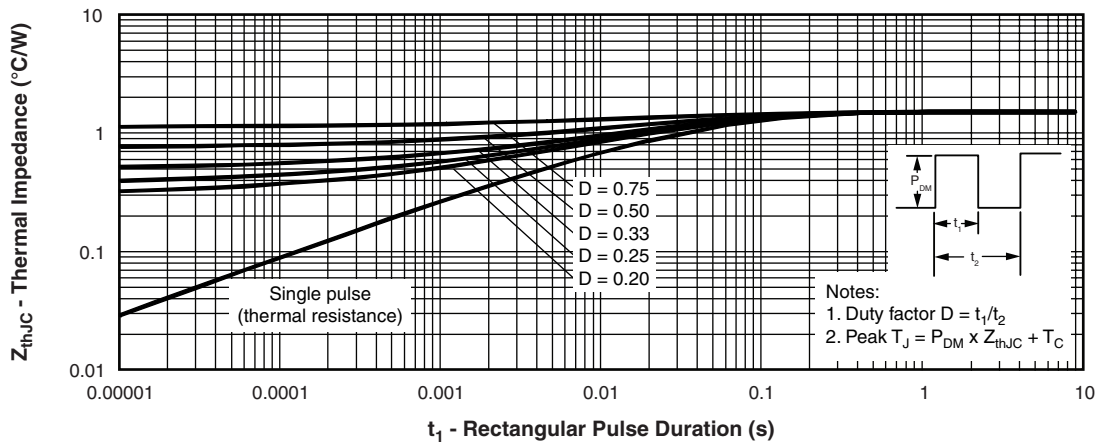


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

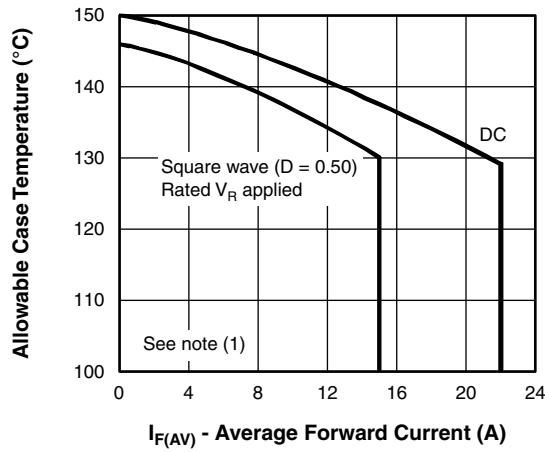


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

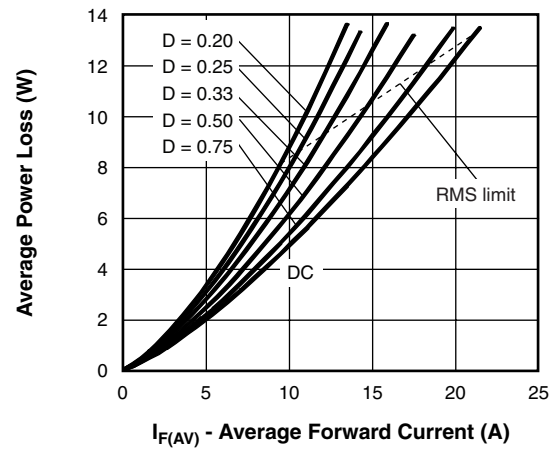


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

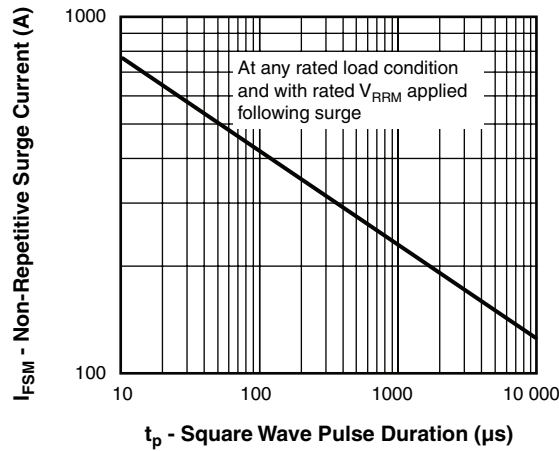


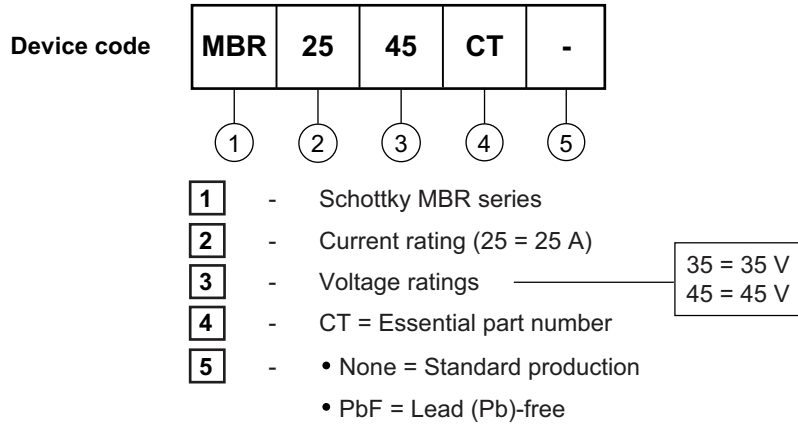
Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R



ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95222
Part marking information	http://www.vishay.com/doc?95225



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